

### OVERVIEW

The 5027 series are miniature crystal oscillator module ICs. The oscillator circuit stage has voltage regulator drive, significantly reducing current consumption and crystal current, compared with existing devices, and significantly reducing the oscillator characteristics supply voltage dependency. There are 3 pad layout package options available for optimized mounting, making these devices ideal for miniature crystal oscillators.

### FEATURES

- Wide range of operating supply voltage: 1.60 to 3.63V
- Regulated voltage drive oscillator circuit for reduced power consumption and crystal drive current
- Optimized low crystal drive current oscillation for miniature crystal units
- 3 pad layout options for mounting
  - 5027A×, M× series: for Flip Chip Bonding
  - 5027B×, N× series : for Wire Bonding (type I)
  - 5027C×, P× series : for Wire Bonding (type II)
- Recommended oscillation frequency range
  - For fundamental oscillator**
    - Low frequency version : 20MHz to 60MHz
    - High frequency version: 60MHz to 100MHz
  - For 3rd overtone oscillator**
    - Low frequency version : 40MHz to 110MHz
- Multi-stage frequency divider for low-frequency output support: 0.9MHz (min)
- Frequency divider built-in (for fundamental oscillator)
  - Selectable by version:  $f_O$ ,  $f_O/2$ ,  $f_O/4$ ,  $f_O/8$ ,  $f_O/16$ ,  $f_O/32$ ,  $f_O/64$
- -40 to 85°C operating temperature range
- Standby function
  - High impedance in standby mode, oscillator stops
- CMOS output duty level (1/2VDD)
- 50 ± 5% output duty
- 15pF output drive capability
- Wafer form (WF5027××)  
Chip form (CF5027××)

### APPLICATIONS

- 3.2 × 2.5, 2.5 × 2.0, 2.0 × 1.6 size miniature crystal oscillator modules

### ORDERING INFORMATION

Device	Package
WF5027××-4	Wafer form
CF5027××-4	Chip form

## SERIES CONFIGURATION

### For Fundamental Oscillator

Operating supply voltage range [V]	Output drive capability [mA]	PAD layout	Recommended oscillation frequency range <sup>*1</sup> [MHz]	Version <sup>*2</sup>						
				f <sub>0</sub> output	f <sub>0</sub> /2 output	f <sub>0</sub> /4 output	f <sub>0</sub> /8 output	f <sub>0</sub> /16 output	f <sub>0</sub> /32 output	f <sub>0</sub> /64 output
1.60 to 3.63	± 4	Flip Chip Bonding	20 to 60	5027A1	5027A2	5027A3	5027A4	5027A5	5027A6	5027A7
			60 to 100	5027AP	5027AQ	5027AR	5027AS	5027AT	5027AV	5027AW
		Wire Bonding Type I	20 to 60	5027B1	5027B2	5027B3	5027B4	5027B5	5027B6	5027B7
			60 to 100	5027BP	5027BQ	5027BR	5027BS	5027BT	5027BV	5027BW
		Wire Bonding Type II	20 to 60	5027C1	5027C2	5027C3	5027C4	5027C5	5027C6	5027C7
			60 to 100	5027CP	5027CQ	5027CR	5027CS	5027CT	5027CV	5027CW

\*1. The recommended oscillation frequency is a yardstick value derived from the crystal used for NPC characteristics authentication. However, the oscillation frequency range is not guaranteed. Specifically, the characteristics can vary greatly due to crystal characteristics and mounting conditions, so the oscillation characteristics of components must be carefully evaluated.

\*2. Wafer form devices have designation WF5027×× and chip form devices have designation CF5027××.

### For 3rd Overtone Oscillator

Operating supply voltage range [V]	Output drive capability [mA]	PAD layout	Recommended oscillation frequency range <sup>*1</sup> [MHz] and version <sup>*2</sup>			
			40 to 50	50 to 65	65 to 85	85 to 110
1.60 to 3.63	± 8	Flip Chip Bonding	5027MA	5027MB	5027MC	5027MD
		Wire Bonding Type I	5027NA	5027NB	5027NC	5027ND
		Wire Bonding Type II	5027PA	5027PB	5027PC	5027PD

\*1. The recommended oscillation frequency is a yardstick value derived from the crystal used for NPC characteristics authentication. However, the oscillation frequency range is not guaranteed. Specifically, the characteristics can vary greatly due to crystal characteristics and mounting conditions, so the oscillation characteristics of components must be carefully evaluated.

\*2. Wafer form devices have designation WF5027×× and chip form devices have designation CF5027××.

## VERSION NAME

Device	Package	Version name
WF5027××-4	Wafer form	<p style="text-align: center;">WF5027□□-4</p> <p>Form WF: Wafer form      CF: Chip (Die) form</p> <p style="text-align: right;">Oscillation frequency range, frequency divider function Pad layout type    A, M: for Flip Chip Bonding                                   B, N: for Wire Bonding (type I)                                   C, P: for Wire Bonding (type II)</p>
CF5027××-4	Chip form	

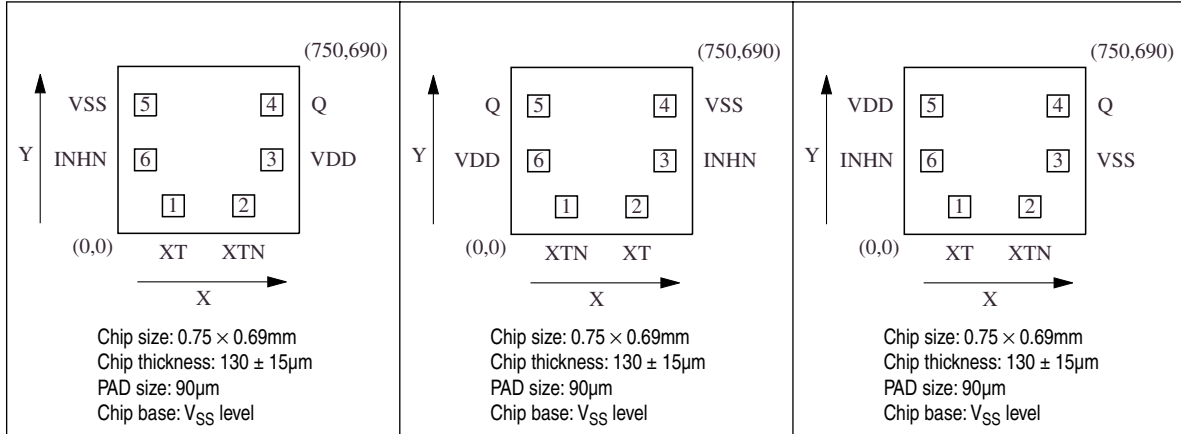
**PAD LAYOUT**

(Unit:  $\mu\text{m}$ )

■ 5027A $\times$ , M $\times$   
(for Flip Chip Bonding)

■ 5027B $\times$ , N $\times$   
(for Wire Bonding (type I))

■ 5027C $\times$ , P $\times$   
(for Wire Bonding (type II))



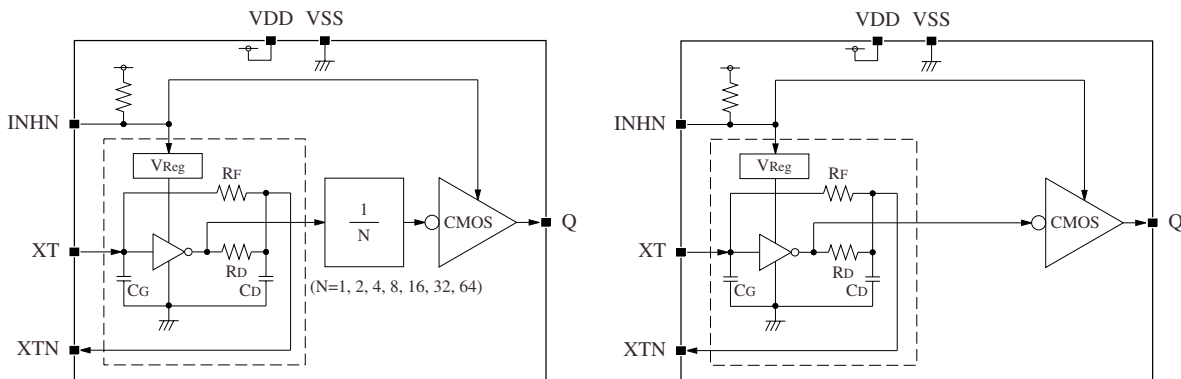
**PAD DIMENSIONS PIN DESCRIPTION**

Pad No.	Pad dimensions [ $\mu\text{m}$ ]		Pad No.			Pin	Name	Description
	X	Y	5027A $\times$ 5027M $\times$	5027B $\times$ 5027N $\times$	5027C $\times$ 5027P $\times$			
1	229	114	1	2	1	XT	Amplifier input	Crystal connection pins. Crystal is connected between XT and XTN.
2	520	114	2	1	2	XTN	Amplifier output	
3	636	304	3	6	5	VDD	(+) supply voltage	-
4	636	531	4	5	4	Q	Output	Output frequency determined by internal circuit to one of $f_O$ , $f_O/2$ , $f_O/4$ , $f_O/8$ , $f_O/16$ , $f_O/32$ , $f_O/64$
5	114	531	5	4	3	VSS	(-) ground	-
6	114	304	6	3	6	INH N	Output state control input	High impedance when LOW (oscillator stops). Power-saving pull-up resistor built-in.

**BLOCK DIAGRAM**

For Fundamental Oscillator

For 3rd Overtone Oscillator



## VERSION DISCRIMINATION INTERNAL COMPONENTS

The 5027 series device version is not determined solely by the mask pattern, but can also be determined by the trimming of internal trimming fuses.

- Version determined by laser trimming:

These chips are produced from a common device by the laser trimming of fuses corresponding to the ordered version, shown in table 1. These devices are shipped for electrical characteristics testing. Laser-trimmed versions are identified externally by the combination of the version name marking (1) and the locations of trimmed fuses (2).

- Version determined by mask pattern:

These chips are fabricated using the mask corresponding to the ordered version, and do not require trimming. Mask-fabricated versions are identified externally by the version name marking (1) only.

Since the 5027 series devices are manufactured using 2 methods, there are 2 types of IC chip available (identified externally) for the same version name. The identification markings for all 5027 series device versions is shown in table 2.

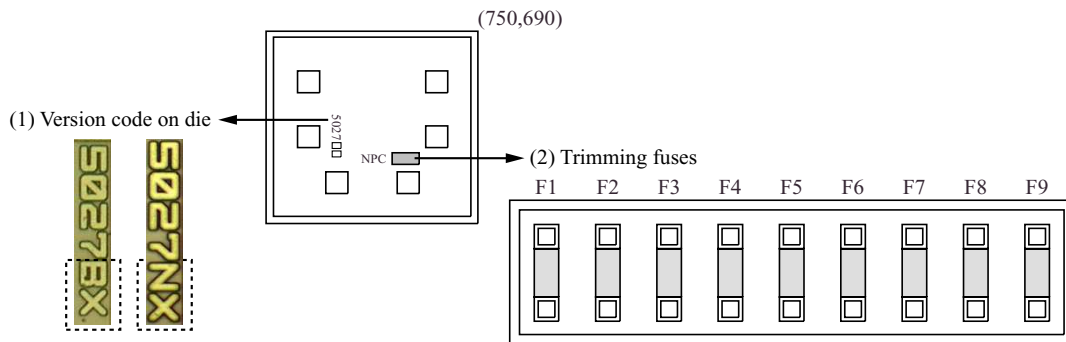


Table 1. Version and trimming fuses (for fundamental oscillator)

Version	Trimming fuse number <sup>*1</sup>				
	F1	F2	F3	F4	F5
5027×1	-	-	-	-	-
5027×2	×	-	-	-	-
5027×3	-	×	-	-	-
5027×4	×	×	-	-	-
5027×5	-	-	×	-	-
5027×6	×	-	×	-	-
5027×7	-	×	×	-	-
5027×P	-	-	-	×	×
5027×Q	×	-	-	×	×
5027×R	-	×	-	×	×
5027×S	×	×	-	×	×
5027×T	-	-	×	×	×
5027×V	×	-	×	×	×
5027×W	-	×	×	×	×

\*1. -: untrimmed, ×: trimmed, F6 to F9 not used

- 5027×1 trimming fuses (untrimmed)



- 5027×2 trimming fuses (F1 link trimmed)



- 5027×3 trimming fuses (F2 link trimmed)



- 5027×4 trimming fuses (F1 and F2 links trimmed)



○ : trimmed device

Table 2. Version and trimming fuses (for 3rd overtone oscillator)

Version	Recommended oscillation frequency range [MHz]	Trimming fuse number <sup>*1</sup>								
		F1	F2	F3	F4	F5	F6	F7	F8	F9
5027×A	40 to 50	-	-	-	-	-	-	×	×	×
5027×B	50 to 65	-	×	-	-	-	-	-	×	×
5027×C	65 to 85	×	×	-	-	×	-	×	-	×
5027×D	85 to 110	-	×	×	×	×	-	×	-	×

\*1. -: untrimmed, ×: trimmed

5027 series

Table 3. Version identification by version name and chip markings (for fundamental oscillator)

Version name	Version set by trimming fuses										Version set by mask pattern											
	Version code on chip	Trimming fuses*1									Version code on chip	Trimming fuses										
		F1	F2	F3	F4	F5	F6	F7	F8	F9		F1 to F9										
5027A1	AX	–	–	–	–	–	Untrimmed	F7	F8	F9	AX	Untrimmed										
5027A2	AX	×	–	–	–	–					A2											
5027A3	AX	–	×	–	–	–					A3											
5027A4	AX	×	×	–	–	–					A4											
5027A5	AX	–	–	×	–	–					A5											
5027A6	AX	×	–	×	–	–					A6											
5027A7	AX	–	×	×	–	–					A7											
5027AP	AX	–	–	–	×	×					AP											
5027AQ	AX	×	–	–	×	×					AQ											
5027AR	AX	–	×	–	×	×					AR											
5027AS	AX	×	×	–	×	×					AS											
5027AT	AX	–	–	×	×	×					AT											
5027AV	AX	×	–	×	×	×					AV											
5027AW	AX	–	×	×	×	×					AW											
5027B1	BX	–	–	–	–	–					Untrimmed		F7	F8	F9	BX	Untrimmed					
5027B2	BX	×	–	–	–	–										B2						
5027B3	BX	–	×	–	–	–										B3						
5027B4	BX	×	×	–	–	–										B4						
5027B5	BX	–	–	×	–	–										B5						
5027B6	BX	×	–	×	–	–										B6						
5027B7	BX	–	×	×	–	–										B7						
5027BP	BX	–	–	–	×	×										BP						
5027BQ	BX	×	–	–	×	×										BQ						
5027BR	BX	–	×	–	×	×										BR						
5027BS	BX	×	×	–	×	×										BS						
5027BT	BX	–	–	×	×	×										BT						
5027BV	BX	×	–	×	×	×										BV						
5027BW	BX	–	×	×	×	×										BW						
5027C1	CX	–	–	–	–	–										Untrimmed		F7	F8	F9	CX	Untrimmed
5027C2	CX	×	–	–	–	–															C2	
5027C3	CX	–	×	–	–	–					C3											
5027C4	CX	×	×	–	–	–					C4											
5027C5	CX	–	–	×	–	–	C5															
5027C6	CX	×	–	×	–	–	C6															
5027C7	CX	–	×	×	–	–	C7															
5027CP	CX	–	–	–	×	×	CP															
5027CQ	CX	×	–	–	×	×	CQ															
5027CR	CX	–	×	–	×	×	CR															
5027CS	CX	×	×	–	×	×	CS															
5027CT	CX	–	–	×	×	×	CT															
5027CV	CX	×	–	×	×	×	CV															
5027CW	CX	–	×	×	×	×	CW															

\*1. –: untrimmed, ×: trimmed

## 5027 series

Table 4. Version identification by version name and chip markings (for 3rd overtone oscillator)

Version name	Version set by trimming fuses										Version set by mask pattern	
	Version code on chip	Trimming fuses <sup>*1</sup>									Version code on chip	Trimming fuses
		F1	F2	F3	F4	F5	F6	F7	F8	F9		F1 to F9
5027MA	<b>MX</b>	–	–	–	–	–	–	×	×	×	<b>MA</b>	Untrimmed
5027MB	<b>MX</b>	–	×	–	–	–	–	–	×	×	<b>MB</b>	
5027MC	<b>MX</b>	×	×	–	–	×	–	×	–	×	<b>MC</b>	
5027MD	<b>MX</b>	–	×	×	×	×	–	×	–	×	<b>MD</b>	
5027NA	<b>NX</b>	–	–	–	–	–	–	×	×	×	<b>NA</b>	
5027NB	<b>NX</b>	–	×	–	–	–	–	–	×	×	<b>NB</b>	
5027NC	<b>NX</b>	×	×	–	–	×	–	×	–	×	<b>NC</b>	
5027ND	<b>NX</b>	–	×	×	×	×	–	×	–	×	<b>ND</b>	
5027PA	<b>PX</b>	–	–	–	–	–	–	×	×	×	<b>PA</b>	
5027PB	<b>PX</b>	–	×	–	–	–	–	–	×	×	<b>PB</b>	
5027PC	<b>PX</b>	×	×	–	–	×	–	×	–	×	<b>PC</b>	
5027PD	<b>PX</b>	–	×	×	×	×	–	×	–	×	<b>PD</b>	

\*1. –: untrimmed, ×: trimmed

## SPECIFICATIONS

### Absolute Maximum Ratings

$$V_{SS} = 0V$$

Parameter	Symbol	Condition	Rating	Unit
Supply voltage range	$V_{DD}$	Between VDD and VSS	-0.5 to +4.0	V
Input voltage range <sup>*1</sup>	$V_{IN}$	Input pins	-0.5 to $V_{DD} + 0.5$	V
Output voltage range <sup>*1</sup>	$V_{OUT}$	Output pins	-0.5 to $V_{DD} + 0.5$	V
Storage temperature range	$T_{STG}$	Wafer form	-65 to +150	°C
Output current	$I_{OUT}$	Q pin	± 20	mA

\*1.  $V_{DD}$  is a  $V_{DD}$  value of recommended operating conditions.

Note. Absolute maximum ratings are the values that must never exceed even for a moment. This product may suffer breakdown if any one of these parameter ratings is exceeded. Operation and characteristics are guaranteed only when the product is operated at recommended supply voltage range.

### Recommended Operating Conditions

#### For Fundamental Oscillator

$$V_{SS} = 0V$$

Parameter	Symbol	Condition	Rating			Unit	
			min	typ	max		
Operating supply voltage	$V_{DD}$	$C_{LOUT} \leq 15pF$	1.60	-	3.63	V	
Input voltage	$V_{IN}$	Input pins	$V_{SS}$	-	$V_{DD}$	V	
Operating temperature	$T_{OPR}$		-40	-	+85	°C	
Oscillation frequency <sup>*1</sup>	$f_O$	5027×1 to 5027×7	20	-	60	MHz	
		5027×P to 5027×W	60	-	100	MHz	
Output frequency	$f_{OUT}$	$C_{LOUT} \leq 15pF$	5027×1 to 5027×7	0.9	-	60	MHz
			5027×P to 5027×W	0.9	-	100	MHz

\*1. The oscillation frequency is a yardstick value derived from the crystal used for NPC characteristics authentication. However, the oscillation frequency range is not guaranteed. Specifically, the characteristics can vary greatly due to crystal characteristics and mounting conditions, so the oscillation characteristics of components must be carefully evaluated.

#### For 3rd Overtone Oscillator

$$V_{SS} = 0V$$

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
Operating supply voltage	$V_{DD}$	$C_{LOUT} \leq 15pF$	1.60	-	3.63	V
Input voltage	$V_{IN}$	Input pins	$V_{SS}$	-	$V_{DD}$	V
Operating temperature	$T_{OPR}$		-40	-	+85	°C
Oscillation frequency <sup>*1</sup>	$f_O$	5027×A	40	-	50	MHz
		5027×B	50	-	65	MHz
		5027×C	65	-	85	MHz
		5027×D	85	-	110	MHz

\*1. The oscillation frequency is a yardstick value derived from the crystal used for NPC characteristics authentication. However, the oscillation frequency range is not guaranteed. Specifically, the characteristics can vary greatly due to crystal characteristics and mounting conditions, so the oscillation characteristics of components must be carefully evaluated.

## Electrical Characteristics

### DC Characteristics

#### For Fundamental Oscillator: Low frequency version (5027×1 to 5027×7)

$V_{DD} = 1.60$  to  $3.63$ V,  $V_{SS} = 0$ V,  $T_a = -40$  to  $+85$ °C unless otherwise noted.

Parameter	Symbol	Condition	Rating			Unit		
			min	typ	max			
HIGH-level output voltage	$V_{OH}$	Q: Measurement cct 3, $I_{OH} = -4$ mA	$V_{DD} - 0.4$	–	–	V		
LOW-level output voltage	$V_{OL}$	Q: Measurement cct 3, $I_{OL} = 4$ mA	–	–	0.4	V		
HIGH-level input voltage	$V_{IH}$	INH, Measurement cct 4	$0.7V_{DD}$	–	–	V		
LOW-level input voltage	$V_{IL}$	INH, Measurement cct 4	–	–	$0.3V_{DD}$	V		
Output leakage current	$I_Z$	Q: Measurement cct 5, INH = LOW	$V_{OH} = V_{DD}$	–	–	10	μA	
			$V_{OL} = V_{SS}$	–10	–	–	μA	
Current consumption*1	$I_{DD}$	5027×1 ( $f_O$ ), Measurement cct 1, no load, INH = open, $f_O = 48$ MHz, $f_{OUT} = 48$ MHz	$V_{DD} = 3.3$ V	–	1.6	2.4	mA	
			$V_{DD} = 2.5$ V	–	1.3	2.0	mA	
			$V_{DD} = 1.8$ V	–	1.0	1.5	mA	
		5027×2 ( $f_O/2$ ), Measurement cct 1, no load, INH = open, $f_O = 48$ MHz, $f_{OUT} = 24$ MHz	$V_{DD} = 3.3$ V	–	1.5	2.3	mA	
			$V_{DD} = 2.5$ V	–	1.2	1.8	mA	
			$V_{DD} = 1.8$ V	–	0.9	1.4	mA	
		5027×3 ( $f_O/4$ ), Measurement cct 1, no load, INH = open, $f_O = 48$ MHz, $f_{OUT} = 12$ MHz	$V_{DD} = 3.3$ V	–	1.3	2.0	mA	
			$V_{DD} = 2.5$ V	–	1.0	1.5	mA	
			$V_{DD} = 1.8$ V	–	0.8	1.2	mA	
		5027×4 ( $f_O/8$ ), Measurement cct 1, no load, INH = open, $f_O = 48$ MHz, $f_{OUT} = 6$ MHz	$V_{DD} = 3.3$ V	–	1.1	1.7	mA	
			$V_{DD} = 2.5$ V	–	0.9	1.4	mA	
			$V_{DD} = 1.8$ V	–	0.75	1.15	mA	
		5027×5 ( $f_O/16$ ), Measurement cct 1, no load, INH = open, $f_O = 48$ MHz, $f_{OUT} = 3$ MHz	$V_{DD} = 3.3$ V	–	1.05	1.6	mA	
			$V_{DD} = 2.5$ V	–	0.85	1.3	mA	
			$V_{DD} = 1.8$ V	–	0.7	1.1	mA	
		5027×6 ( $f_O/32$ ), Measurement cct 1, no load, INH = open, $f_O = 48$ MHz, $f_{OUT} = 1.5$ MHz	$V_{DD} = 3.3$ V	–	1.0	1.5	mA	
			$V_{DD} = 2.5$ V	–	0.85	1.3	mA	
			$V_{DD} = 1.8$ V	–	0.7	1.1	mA	
		5027×7 ( $f_O/64$ ), Measurement cct 1, no load, INH = open, $f_O = 60$ MHz, $f_{OUT} = 0.94$ MHz	$V_{DD} = 3.3$ V	–	1.0	1.5	mA	
			$V_{DD} = 2.5$ V	–	0.85	1.3	mA	
			$V_{DD} = 1.8$ V	–	0.7	1.1	mA	
		Standby current	$I_{ST}$	Measurement cct 1, INH = LOW	–	–	10	μA
		INH pull-up resistance	$R_{UP1}$	Measurement cct 6	0.4	1.5	8	MΩ
			$R_{UP2}$		30	70	150	kΩ
Oscillator feedback resistance	$R_f$		50	100	200	kΩ		
Oscillator capacitance	$C_G$	Design value (a monitor pattern on a wafer is tested), Excluding parasitic capacitance.	4.8	6	7.2	pF		
	$C_D$		8	10	12	pF		

\*1. The consumption current  $I_{DD}$  ( $C_{LOUT}$ ) with a load capacitance ( $C_{LOUT}$ ) connected to the Q pin is given by the following equation, where  $I_{DD}$  is the no-load consumption current and  $f_{OUT}$  is the output frequency.

$$I_{DD} (C_{LOUT}) [\text{mA}] = I_{DD} [\text{mA}] + C_{LOUT} [\text{pF}] \times V_{DD} [\text{V}] \times f_{OUT} [\text{MHz}] \times 10^{-3}$$

5027 series

**For Fundamental Oscillator: High frequency version (5027×P to 5027×W)**

$V_{DD} = 1.60$  to  $3.63V$ ,  $V_{SS} = 0V$ ,  $T_a = -40$  to  $+85^{\circ}C$  unless otherwise noted.

Parameter	Symbol	Condition	Rating			Unit		
			min	typ	max			
HIGH-level output voltage	$V_{OH}$	Q: Measurement cct 3, $I_{OH} = -4mA$	$V_{DD} - 0.4$	–	–	V		
LOW-level output voltage	$V_{OL}$	Q: Measurement cct 3, $I_{OL} = 4mA$	–	–	0.4	V		
HIGH-level input voltage	$V_{IH}$	INH, Measurement cct 4	$0.7V_{DD}$	–	–	V		
LOW-level input voltage	$V_{IL}$	INH, Measurement cct 4	–	–	$0.3V_{DD}$	V		
Output leakage current	$I_Z$	Q: Measurement cct 5, INH = LOW	$V_{OH} = V_{DD}$	–	–	10	$\mu A$	
			$V_{OL} = V_{SS}$	–10	–	–	$\mu A$	
Current consumption*1	$I_{DD}$	5027×P ( $f_O$ ), Measurement cct 1, no load, INH = open, $f_O = 80MHz$ , $f_{OUT} = 80MHz$	$V_{DD} = 3.3V$	–	2.5	3.8	mA	
			$V_{DD} = 2.5V$	–	2.0	3.0	mA	
			$V_{DD} = 1.8V$	–	1.6	2.4	mA	
		5027×Q ( $f_O/2$ ), Measurement cct 1, no load, INH = open, $f_O = 80MHz$ , $f_{OUT} = 40MHz$	$V_{DD} = 3.3V$	–	2.4	3.6	mA	
			$V_{DD} = 2.5V$	–	1.9	2.9	mA	
			$V_{DD} = 1.8V$	–	1.5	2.3	mA	
		5027×R ( $f_O/4$ ), Measurement cct 1, no load, INH = open, $f_O = 80MHz$ , $f_{OUT} = 20MHz$	$V_{DD} = 3.3V$	–	1.8	2.7	mA	
			$V_{DD} = 2.5V$	–	1.5	2.3	mA	
			$V_{DD} = 1.8V$	–	1.2	1.6	mA	
		5027×S ( $f_O/8$ ), Measurement cct 1, no load, INH = open, $f_O = 80MHz$ , $f_{OUT} = 10MHz$	$V_{DD} = 3.3V$	–	1.7	2.6	mA	
			$V_{DD} = 2.5V$	–	1.4	2.1	mA	
			$V_{DD} = 1.8V$	–	1.1	1.7	mA	
		5027×T ( $f_O/16$ ), Measurement cct 1, no load, INH = open, $f_O = 80MHz$ , $f_{OUT} = 5MHz$	$V_{DD} = 3.3V$	–	1.6	2.4	mA	
			$V_{DD} = 2.5V$	–	1.3	2.0	mA	
			$V_{DD} = 1.8V$	–	1.0	1.5	mA	
		5027×V ( $f_O/32$ ), Measurement cct 1, no load, INH = open, $f_O = 80MHz$ , $f_{OUT} = 2.5MHz$	$V_{DD} = 3.3V$	–	1.5	2.3	mA	
			$V_{DD} = 2.5V$	–	1.2	1.8	mA	
			$V_{DD} = 1.8V$	–	1.0	1.5	mA	
		5027×W ( $f_O/64$ ), Measurement cct 1, no load, INH = open, $f_O = 80MHz$ , $f_{OUT} = 1.25MHz$	$V_{DD} = 3.3V$	–	1.5	2.3	mA	
			$V_{DD} = 2.5V$	–	1.2	1.8	mA	
			$V_{DD} = 1.8V$	–	1.0	1.5	mA	
		Standby current	$I_{ST}$	Measurement cct 1, INH = LOW	–	–	10	$\mu A$
		INH pull-up resistance	$R_{UP1}$	Measurement cct 6	0.4	1.5	8	$M\Omega$
			$R_{UP2}$		30	70	150	$k\Omega$
Oscillator feedback resistance	$R_f$		50	100	200	$k\Omega$		
Oscillator capacitance	$C_G$	Design value (a monitor pattern on a wafer is tested), Excluding parasitic capacitance.	1.6	2	2.4	pF		
	$C_D$		3.2	4	4.8	pF		

\*1. The consumption current  $I_{DD}$  ( $C_{LOUT}$ ) with a load capacitance ( $C_{LOUT}$ ) connected to the Q pin is given by the following equation, where  $I_{DD}$  is the no-load consumption current and  $f_{OUT}$  is the output frequency.

$$I_{DD} (C_{LOUT}) [mA] = I_{DD} [mA] + C_{LOUT} [pF] \times V_{DD} [V] \times f_{OUT} [MHz] \times 10^{-3}$$

5027 series

**For 3rd Overtone Oscillator (5027×A to 5027×D)**

$V_{DD} = 1.60$  to  $3.63V$ ,  $V_{SS} = 0V$ ,  $T_a = -40$  to  $+85^{\circ}C$  unless otherwise noted.

Parameter	Symbol	Condition	Rating			Unit	
			min	typ	max		
HIGH-level output voltage	$V_{OH}$	Q: Measurement cct 3, $I_{OH} = -8mA$ , $V_{DD} = 2.25$ to $3.63V$	$V_{DD} - 0.4$	-	-	V	
		Q: Measurement cct 3, $I_{OH} = -4mA$ , $V_{DD} = 1.60$ to $2.25V$	$V_{DD} - 0.4$	-	-	V	
LOW-level output voltage	$V_{OL}$	Q: Measurement cct 3, $I_{OL} = 8mA$ , $V_{DD} = 2.25$ to $3.63V$	-	-	0.4	V	
		Q: Measurement cct 3, $I_{OL} = 4mA$ , $V_{DD} = 1.60$ to $2.25V$	-	-	0.4	V	
HIGH-level input voltage	$V_{IH}$	INH, Measurement cct 4	$0.7V_{DD}$	-	-	V	
LOW-level input voltage	$V_{IL}$	INH, Measurement cct 4	-	-	$0.3V_{DD}$	V	
Output leakage current	$I_Z$	Q: Measurement cct 5, INH = LOW	$V_{OH} = V_{DD}$	-	-	10	$\mu A$
			$V_{OL} = V_{SS}$	-10	-	-	$\mu A$
Current consumption <sup>*1</sup>	$I_{DD}$	5027×A, Measurement cct 1, no load, INH = open, $f_O = 48MHz$	$V_{DD} = 3.3V$	-	3.6	5.4	mA
			$V_{DD} = 2.5V$	-	3.0	4.5	mA
			$V_{DD} = 1.8V$	-	2.6	3.9	mA
		5027×B, Measurement cct 1, no load, INH = open, $f_O = 54MHz$	$V_{DD} = 3.3V$	-	3.8	5.7	mA
			$V_{DD} = 2.5V$	-	3.2	4.8	mA
			$V_{DD} = 1.8V$	-	2.8	4.2	mA
		5027×C, Measurement cct 1, no load, INH = open, $f_O = 85MHz$	$V_{DD} = 3.3V$	-	4.8	7.2	mA
			$V_{DD} = 2.5V$	-	4.0	6.0	mA
			$V_{DD} = 1.8V$	-	3.4	5.1	mA
		5027×D, Measurement cct 1, no load, INH = open, $f_O = 100MHz$	$V_{DD} = 3.3V$	-	5.3	8.0	mA
			$V_{DD} = 2.5V$	-	4.4	6.6	mA
			$V_{DD} = 1.8V$	-	3.6	5.4	mA
Standby current	$I_{ST}$	Measurement cct 1, INH = LOW	-	-	10	$\mu A$	
INH pull-up resistance	$R_{UP1}$	Measurement cct 6	0.4	1.5	8	M $\Omega$	
	$R_{UP2}$		30	70	150	k $\Omega$	
Oscillator feedback resistance	$R_f$	5027×A	2.6	3.8	5.0	k $\Omega$	
		5027×B	2.2	3.2	4.2	k $\Omega$	
		5027×C	1.9	2.8	3.7	k $\Omega$	
		5027×D	1.9	2.8	3.7	k $\Omega$	
Oscillator capacitance	$C_G$	Design value (a monitor pattern on a wafer is tested), Excluding parasitic capacitance.	5027×A	9.6	12	14.4	pF
			5027×B	6.4	8	9.6	pF
			5027×C	4.8	6	7.2	pF
			5027×D	1.6	2	2.4	pF
	$C_D$	Design value (a monitor pattern on a wafer is tested), Excluding parasitic capacitance.	5027×A	9.6	12	14.4	pF
			5027×B	9.6	12	14.4	pF
			5027×C	6.4	8	9.6	pF
			5027×D	4.8	6	7.2	pF

\*1. The consumption current  $I_{DD}$  ( $C_{LOUT}$ ) with a load capacitance ( $C_{LOUT}$ ) connected to the Q pin is given by the following equation, where  $I_{DD}$  is the no-load consumption current and  $f_{OUT}$  is the output frequency.

$$I_{DD} (C_{LOUT}) [mA] = I_{DD} [mA] + C_{LOUT} [pF] \times V_{DD} [V] \times f_{OUT} [MHz] \times 10^{-3}$$

## AC Characteristics

### For Fundamental Oscillator (5027×1 to 5027×7, 5027×P to 5027×W)

$V_{DD} = 1.60$  to  $3.63V$ ,  $V_{SS} = 0V$ ,  $T_a = -40$  to  $+85^\circ C$  unless otherwise noted.

Parameter	Symbol	Condition	Rating			Unit	
			min	typ	max		
Output rise time	$t_{r1}$	Measurement cct 1, $C_{LOUT} = 15pF$ , $0.1V_{DD}$ to $0.9V_{DD}$	$V_{DD} = 2.25$ to $3.36V$	–	2.0	4.5	ns
	$t_{r2}$		$V_{DD} = 1.60$ to $2.25V$	–	3.0	5.0	ns
Output fall time	$t_{f1}$	Measurement cct 1, $C_{LOUT} = 15pF$ , $0.9V_{DD}$ to $0.1V_{DD}$	$V_{DD} = 2.25$ to $3.36V$	–	2.0	4.5	ns
	$t_{f2}$		$V_{DD} = 1.60$ to $2.25V$	–	3.0	5.0	ns
Output duty cycle	Duty	Measurement cct 1, $T_a = 25^\circ C$ , $C_{LOUT} = 15pF$	45	50	55	%	
Output disable delay time	$t_{OD}$	Measurement cct 2, $T_a = 25^\circ C$ , $C_{LOUT} \leq 15pF$	–	–	50	$\mu s$	

### For 3rd Overtone Oscillator (5027×A to 5027×D)

$V_{DD} = 1.60$  to  $3.63V$ ,  $V_{SS} = 0V$ ,  $T_a = -40$  to  $+85^\circ C$  unless otherwise noted.

Parameter	Symbol	Condition	Rating			Unit	
			min	typ	max		
Output rise time	$t_{r1}$	Measurement cct 1, $C_{LOUT} = 15pF$ , $0.1V_{DD}$ to $0.9V_{DD}$	$V_{DD} = 2.25$ to $3.36V$	–	1.2	3.0	ns
	$t_{r2}$		$V_{DD} = 1.60$ to $2.25V$	–	1.6	4.0	ns
Output fall time	$t_{f1}$	Measurement cct 1, $C_{LOUT} = 15pF$ , $0.9V_{DD}$ to $0.1V_{DD}$	$V_{DD} = 2.25$ to $3.36V$	–	1.2	3.0	ns
	$t_{f2}$		$V_{DD} = 1.60$ to $2.25V$	–	1.6	4.0	ns
Output duty cycle	Duty	Measurement cct 1, $T_a = 25^\circ C$ , $C_{LOUT} = 15pF$	45	50	55	%	
Output disable delay time	$t_{OD}$	Measurement cct 2, $T_a = 25^\circ C$ , $C_{LOUT} \leq 15pF$	–	–	50	$\mu s$	

## Timing chart

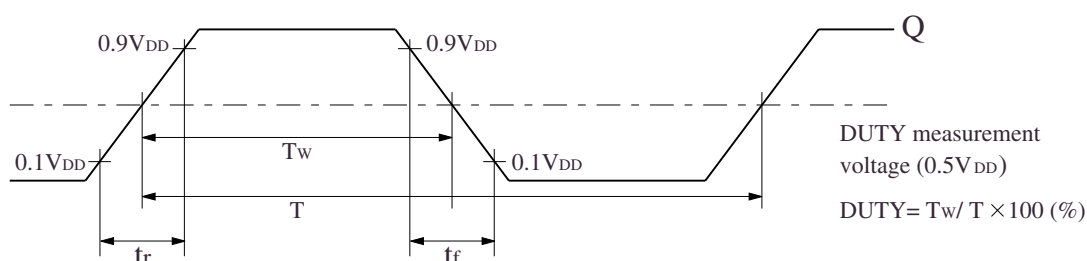
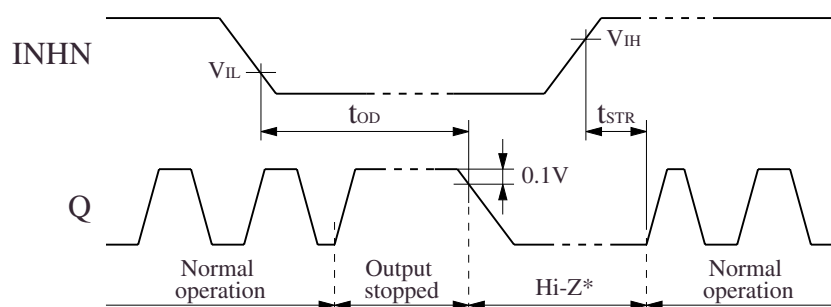


Figure 1. Output switching waveform



When INHN goes HIGH to LOW, the Q output goes HIGH once and then becomes high impedance.

When INHN goes LOW to HIGH, the Q output goes from high impedance to normal output operation after the oscillation start-up time " $t_{STR}$ " (oscillation detector function).

\*) The high-impedance interval in the figure is shown as a LOW level due to the  $1k\Omega$  pull-down resistor connected to the Q pin (see "Measurement circuit 2" in the "Measurement Circuits" section).

Figure 2. Output disable and oscillation start timing chart

## FUNCTIONAL DESCRIPTION

### Standby Function

When INHN goes LOW, the Q output becomes high impedance.

INHN	Q	Oscillator
HIGH (or open)	Frequency output	Normal operation
LOW	High impedance	Stopped

### Power-saving Pull-up Resistor

The INHN pin pull-up resistance  $R_{UP1}$  or  $R_{UP2}$  changes in response to the input level (HIGH or LOW). When INHN is tied LOW level, the pull-up resistance is large ( $R_{UP1}$ ), reducing the current consumed by the resistance. When INHN is left open circuit, the pull-up resistance is small ( $R_{UP2}$ ), which increases the input susceptibility to external noise. However, the pull-up resistance ties the INHN pin HIGH level to prevent external noise from unexpectedly stopping the output.

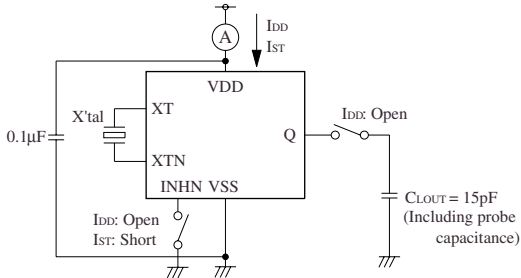
### Oscillation Detector Function

The 5027 series also feature an oscillation detector circuit. This circuit functions to disable the outputs until the oscillator circuit starts and oscillation becomes stable. This alleviates the danger of abnormal oscillator output at oscillator start-up when power is applied or when INHN is switched.

## MEASUREMENT CIRCUITS

### Measurement cct 1

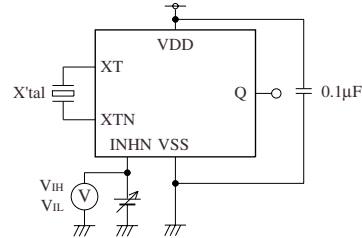
Measurement parameter:  $I_{DD}$ ,  $I_{ST}$ , Duty,  $t_r$ ,  $t_f$



Note: The AC characteristics are observed using an oscilloscope on pin Q.

### Measurement cct 4

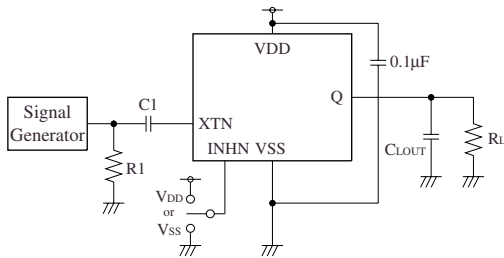
Measurement parameter:  $V_{IH}$ ,  $V_{IL}$



$V_{IH}$ : Voltage in  $V_{SS}$  to  $V_{DD}$  transition that changes the output state.  
 $V_{IL}$ : Voltage in  $V_{DD}$  to  $V_{SS}$  transition that changes the output state.  
 INHN has an oscillation stop function.

### Measurement cct 2

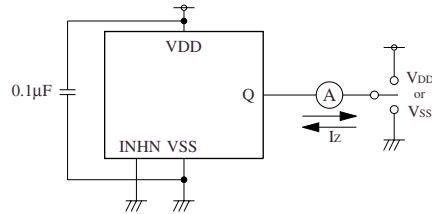
Measurement parameter:  $t_{OD}$



XTN input signal: 1Vp-p, sine wave  
 $C_1$ : 0.001µF       $C_{LOUT}$ : 15pF  
 $R_1$ : 50Ω           $R_L$ : 1kΩ

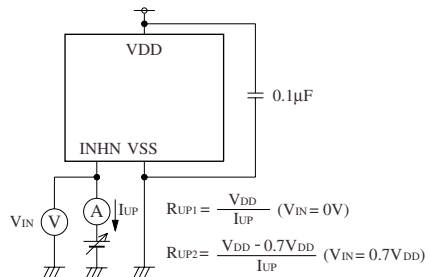
### Measurement cct 5

Measurement parameter:  $I_Z$



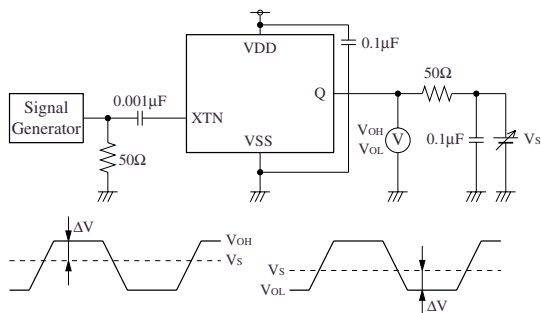
### Measurement cct 6

Measurement parameter:  $R_{UP1}$ ,  $R_{UP2}$



### Measurement cct 3

Measurement parameter:  $V_{OH}$ ,  $V_{OL}$



$V_S$  adjusted such that  $\Delta V = 50 \times I_{OH}$ .       $V_S$  adjusted such that  $\Delta V = 50 \times I_{OL}$ .

XTN input signal: 1Vp-p, sine wave

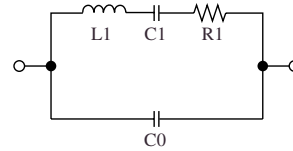
## TYPICAL PERFORMANCE (for fundamental oscillator)

The following characteristics measured using the crystal below. Note that the characteristics will vary with the crystal used.

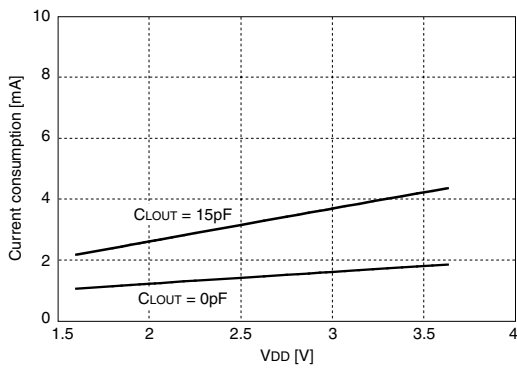
■ Crystal used for measurement

Parameter	$f_0 = 48\text{MHz}$	$f_0 = 80\text{MHz}$
$C_0$ [pF]	1.6	2.1
$R_1$ [ $\Omega$ ]	12	10

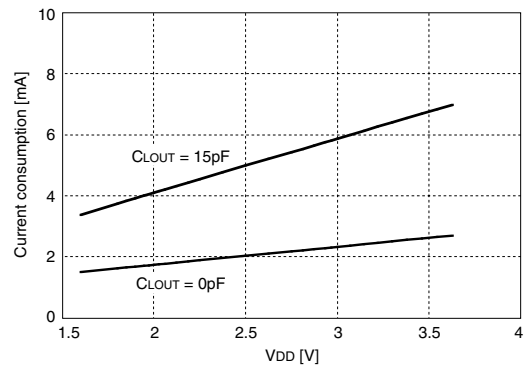
■ Crystal parameters



### Current Consumption

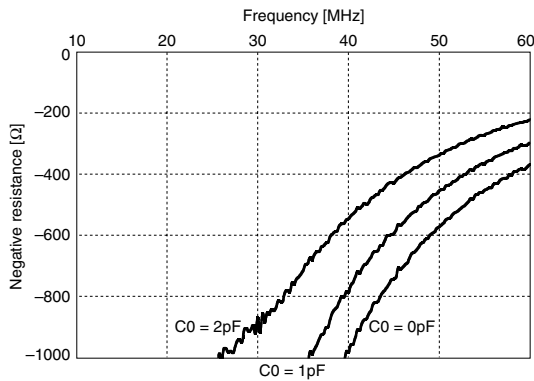


5027A1,  $f_{OUT} = 48\text{MHz}$ ,  $T_a = 25^\circ\text{C}$

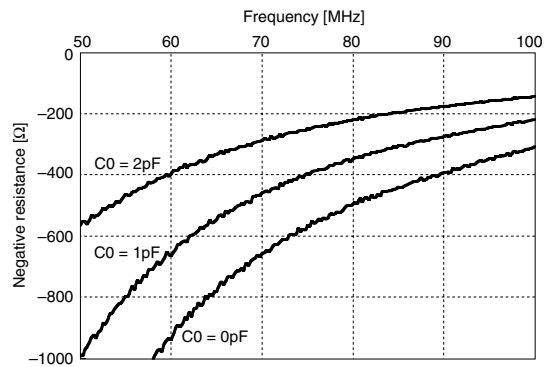


5027AP,  $f_{OUT} = 80\text{MHz}$ ,  $T_a = 25^\circ\text{C}$

### Negative Resistance



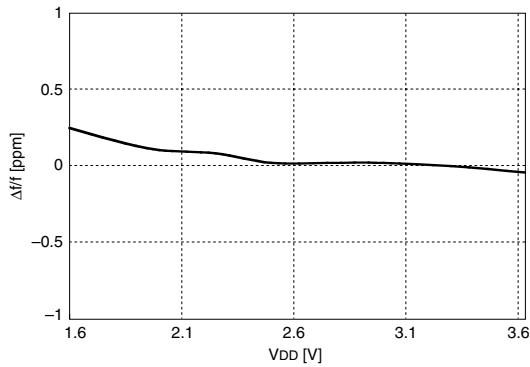
5027x1 to x7,  $V_{DD} = 3.3\text{V}$ ,  $T_a = 25^\circ\text{C}$



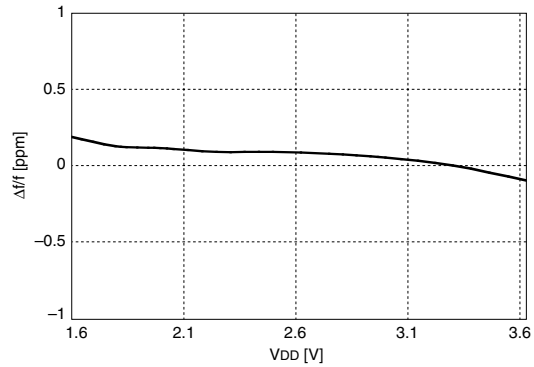
5027xP to xW,  $V_{DD} = 3.3\text{V}$ ,  $T_a = 25^\circ\text{C}$

Characteristics are measured with a capacitance  $C_0$ , representing the crystal equivalent circuit  $C_0$  capacitance, connected between the XT and XTN pins. Measurements are performed with Agilent 4396B using the NPC test jig. Characteristics may vary with measurement jig and measurement conditions.

### Frequency Deviation by Supply Voltage Change

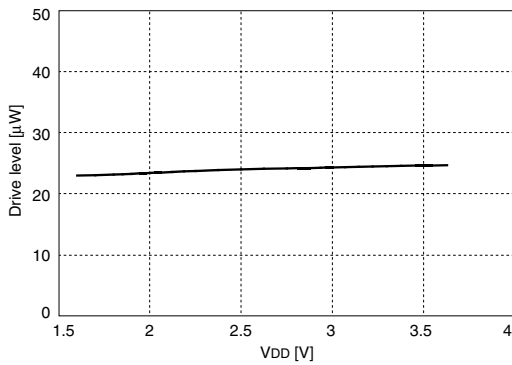


5027×1 to ×7,  $f_{OUT} = 48\text{MHz}$ ,  
3.3V standard,  $T_a = 25^\circ\text{C}$

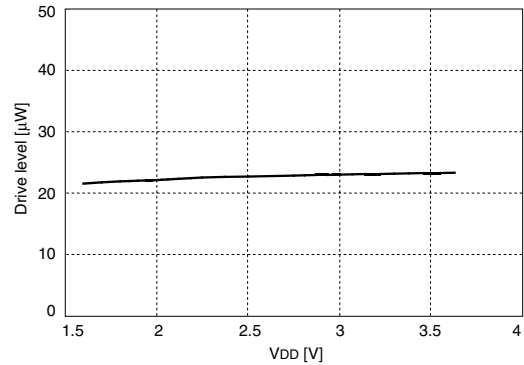


5027×P to ×W,  $f_{OUT} = 80\text{MHz}$ ,  
3.3V standard,  $T_a = 25^\circ\text{C}$

### Drive Level



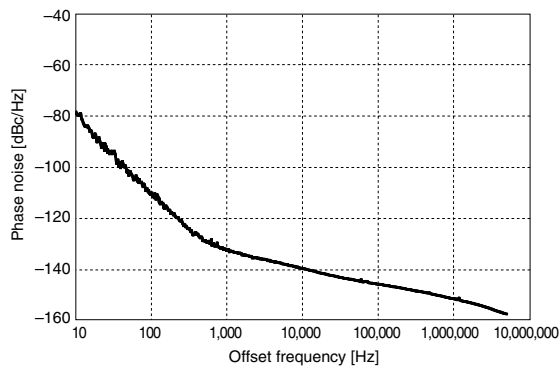
5027×1 to ×7,  $f_{OUT} = 48\text{MHz}$ ,  $T_a = 25^\circ\text{C}$



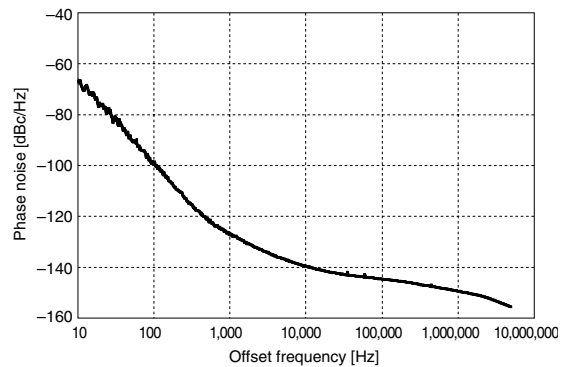
5027×P to ×W,  $f_{OUT} = 80\text{MHz}$ ,  $T_a = 25^\circ\text{C}$

### Phase Noise

Measurement equipment: Agilent E5052 Signal Source Analyzer



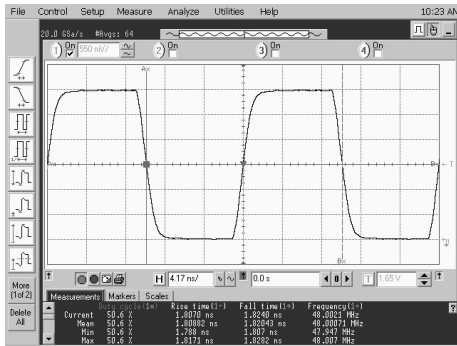
5027A1,  $V_{DD} = 3.3\text{V}$ ,  $f_{OSC} = f_{OUT} = 48\text{MHz}$ ,  
 $T_a = 25^\circ\text{C}$



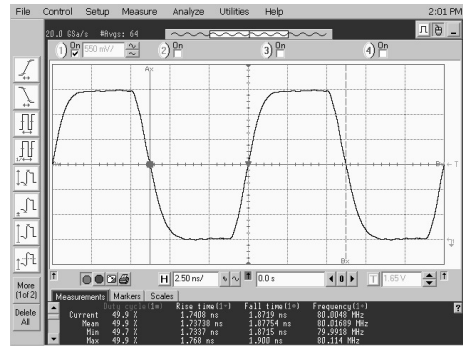
5027AP,  $V_{DD} = 3.3\text{V}$ ,  $f_{OSC} = f_{OUT} = 80\text{MHz}$ ,  
 $T_a = 25^\circ\text{C}$

## Output Waveform

Measurement equipment: Agilent 54855A Oscilloscope



5027A1,  $V_{DD} = 3.3V$ ,  $f_{OUT} = 48MHz$ ,  
 $C_{LOUT} = 15pF$ ,  $T_a = 25^{\circ}C$



5027AP,  $V_{DD} = 3.3V$ ,  $f_{OUT} = 80MHz$ ,  
 $C_{LOUT} = 15pF$ ,  $T_a = 25^{\circ}C$

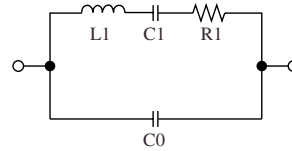
### TYPICAL PERFORMANCE (for 3rd overtone oscillator)

The following characteristics measured using the crystal below. Note that the characteristics will vary with the crystal used.

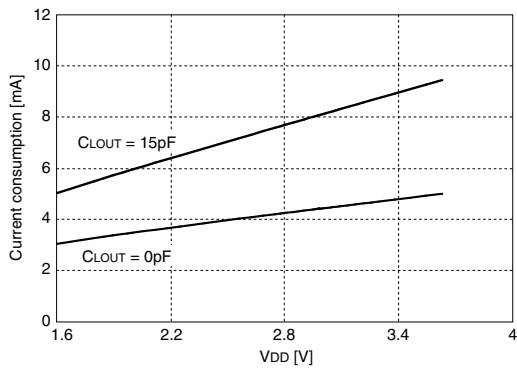
■ Crystal used for measurement

Parameter	$f_0 = 85\text{MHz}$	$f_0 = 100\text{MHz}$
$C_0$ [pF]	0.9	1.2
$R_1$ [ $\Omega$ ]	56	45

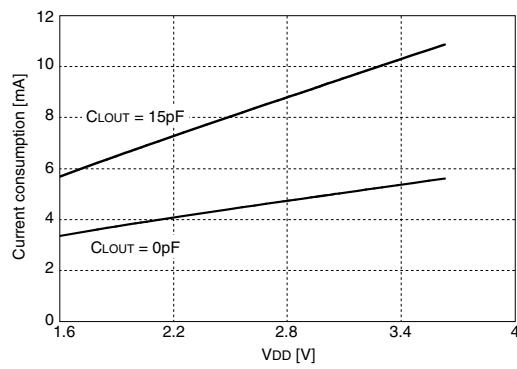
■ Crystal parameters



### Current Consumption

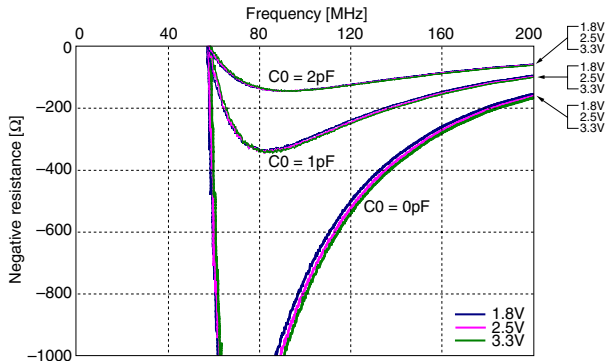


5027xD,  $f_{OUT} = 85\text{MHz}$ ,  $T_a = 25^\circ\text{C}$



5027AP,  $f_{OUT} = 100\text{MHz}$ ,  $T_a = 25^\circ\text{C}$

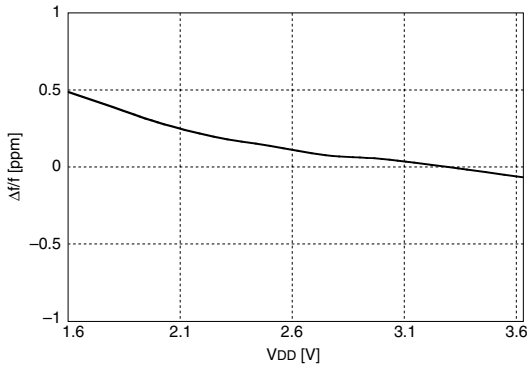
### Negative Resistance



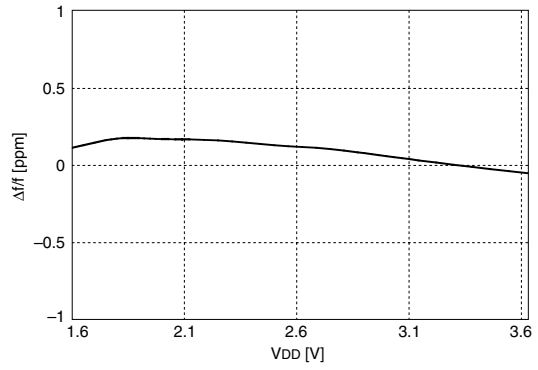
5027xD,  $T_a = 25^\circ\text{C}$ , recommended operating frequency range: 85MHz to 110MHz

Characteristics are measured with a capacitance  $C_0$ , representing the crystal equivalent circuit  $C_0$  capacitance, connected between the XT and XTN pins. Measurements are performed with Agilent 4396B using the NPC test jig. Characteristics may vary with measurement jig and measurement conditions.

**Frequency Deviation by Supply Voltage Change**

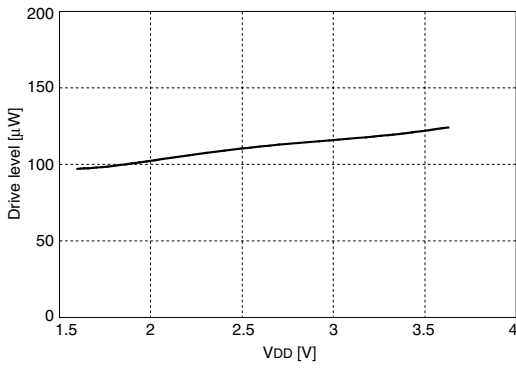


5027×D,  $f_{OUT} = 85\text{MHz}$ , 3.3V standard,  $T_a = 25^\circ\text{C}$

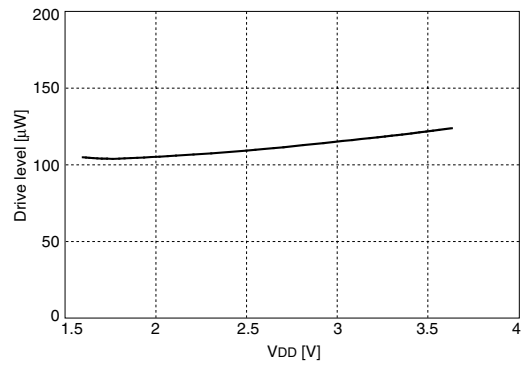


5027×D,  $f_{OUT} = 100\text{MHz}$ , 3.3V standard,  $T_a = 25^\circ\text{C}$

**Drive Level**



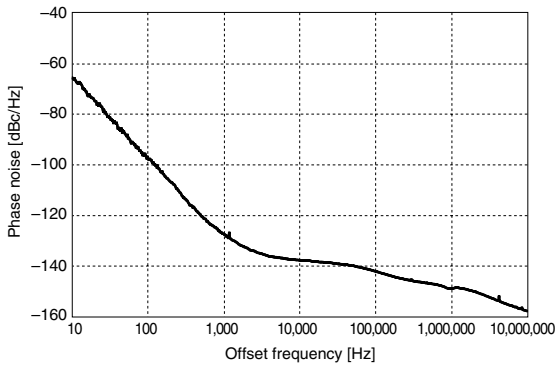
5027×D,  $f_{OUT} = 85\text{MHz}$ ,  $T_a = 25^\circ\text{C}$



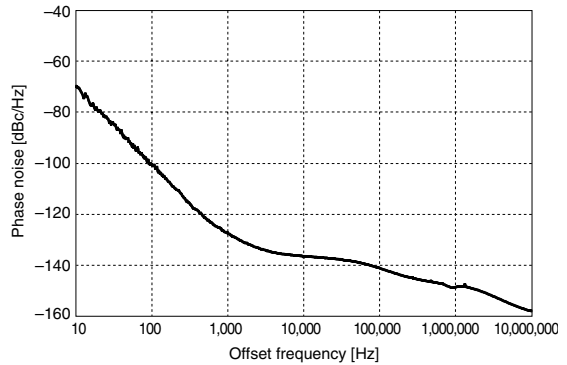
5027×D,  $f_{OUT} = 100\text{MHz}$ ,  $T_a = 25^\circ\text{C}$

**Phase Noise**

Measurement equipment: Agilent E5052 Signal Source Analyzer



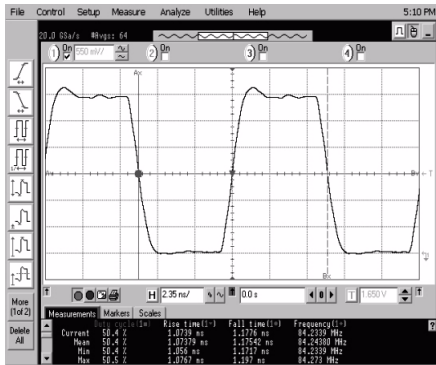
5027×D,  $V_{DD} = 3.3\text{V}$ ,  $f_{OSC} = f_{OUT} = 85\text{MHz}$ ,  $T_a = 25^\circ\text{C}$



5027×D,  $V_{DD} = 3.3\text{V}$ ,  $f_{OSC} = f_{OUT} = 100\text{MHz}$ ,  $T_a = 25^\circ\text{C}$

## Output Waveform

Measurement equipment: Agilent 54855A Oscilloscope



5027×D,  $V_{DD} = 3.3V$ ,  $f_{OUT} = 85MHz$ ,  
 $C_{LOUT} = 15pF$ ,  $T_a = 25^{\circ}C$



5027×D,  $V_{DD} = 3.3V$ ,  $f_{OUT} = 100MHz$ ,  
 $C_{LOUT} = 15pF$ ,  $T_a = 25^{\circ}C$

Please pay your attention to the following points at time of using the products shown in this document.

1. The products shown in this document (hereinafter "Products") are designed and manufactured to the generally accepted standards of reliability as expected for use in general electronic and electrical equipment, such as personal equipment, machine tools and measurement equipment. The Products are not designed and manufactured to be used in any other special equipment requiring extremely high level of reliability and safety, such as aerospace equipment, nuclear power control equipment, medical equipment, transportation equipment, disaster prevention equipment, security equipment. The Products are not designed and manufactured to be used for the apparatus that exerts harmful influence on the human lives due to the defects, failure or malfunction of the Products. If you wish to use the Products in that apparatus, please contact our sales section in advance.  
In the event that the Products are used in such apparatus without our prior approval, we assume no responsibility whatsoever for any damages resulting from the use of that apparatus.
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The logo for NPC (Seiko NPC Corporation) consists of the letters 'NPC' in a bold, black, sans-serif font. The letters are closely spaced and have a slightly irregular, hand-drawn appearance.

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